## NSN 5961-01-411-6535

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-411-6535 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 working peak reverse voltage and 420.0 reverse voltage, total rms **Current Rating Per Characteristic:** 300.00 amperes forward current, average preset and 60.00 amperes forward current, average blank and 15.00 amperes forward current, average absolute **Test Data Document:** 30003-2037as769 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No